



UNITED STATES PATENT AND TRADEMARK OFFICE

COMMISSIONER FOR PATENTS
UNITED STATES PATENT AND TRADEMARK OFFICE
WASHINGTON, D.C. 20231
www.uspto.gov

BIBDATASHEET

Bib Data Sheet

CONFIRMATION NO. 2895

SERIAL NUMBER 10/681,280	FILING DATE 10/09/2003 RULE	CLASS 365	GROUP ART UNIT 2824	ATTORNEY DOCKET NO.
-----------------------------	---------------------------------------	--------------	------------------------	------------------------

APPLICANTS

Tatsuya Ishii, Tokyo, JAPAN;

Hitoshi Miwa, Tokyo, JAPAN;

Osamu Tsuchiya, Tokyo, JAPAN; Shooji Kubono, Tokyo, JAPAN;

**** CONTINUING DATA *******

This application is a CON of 10/388,444 03/17/2003 PAT 6,683,811
which is a CON of 10/095,565 03/13/2002 PAT 6,567,311
which is a CON of 09/961,300 09/25/2001 PAT 6,385,092
which is a CON of 09/714,552 11/17/2000 PAT 6,392,932
which is a CON of 09/468,329 12/21/1999 PAT 6,157,573
which is a CON of 09/342,231 06/29/1999 PAT 6,023,425
which is a CON of 09/135,175 08/18/1998 PAT 5,982,668
which is a CON of 08/889,191 07/08/1997 PAT 5,867,428

HN(YES)

**** FOREIGN APPLICATIONS *******

JAPAN 8-178965 07/09/1996

JAPAN 9-126793 05/16/1997

HN(YES)

IF REQUIRED, FOREIGN FILING LICENSE GRANTED

**** 03/09/2004**

Foreign Priority claimed <input checked="" type="checkbox"/> yes <input type="checkbox"/> no	STATE OR	SHEETS	TOTAL	INDEPENDENT
35 USC 119 (a-d) conditions met <input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> Met after Allowance	COUNTRY	DRAWING	CLAIMS	CLAIMS
Verified and Acknowledged Examiner's Signature: <u>HN NGUYEN</u> Initials: <u>HN</u>	JAPAN	19	9	2

ADDRESS

MATTINGLY, STANGER & MALUR, P.C.

Suite 370

1800 Diagonal Road

Alexandria, VA

22314

TITLE

Nonvolatile memory system, semiconductor memory, and writing method